



BSS138K

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
50V	3.5Ω @ V _{GS} = 10V	0.31A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Load switches

Low On-Resistance Low Input Capacitance

- Fast Switching Speed
- **ESD** Protected Gate

Features and Benefits

- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

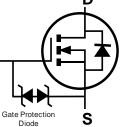
50V N-CHANNEL ENHANCEMENT MODE MOSFET

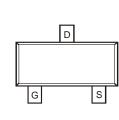
Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)

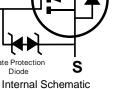








Top View





Ordering Information (Note 4)

Part Number	Paakago	Packing			
Fait Nulliber	Package	Qty.	Carrier		
BSS138K-7	SOT23	3,000	Tape & Reel		
BSS138K-13	SOT23	10,000	Tape & Reel		

G

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

38K	ΥM

38K = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: L = 2024) M = Month (ex: 9 = September)

Date Code Key

Date Obuc Key												
Year	2017	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	E	-	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		Vdss	50	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 6) $V_{GS} = 10V$ State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State State Stat		ID	0.31 0.25	A
Maximum Continuous Body Diode Forward Curro	ent (Note 6)	ls	0.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)	ldм	0.8	А

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.38	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	338	°C/W
Total Power Dissipation (Note 6)		PD	0.54	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	237	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

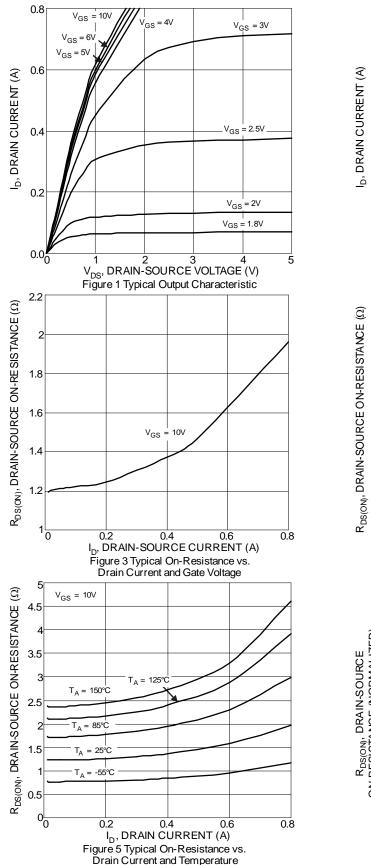
Characteristic	5	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 7)									
Drain-Source Breakdown Voltage		BV _{DSS}	50	_	—	V	$V_{GS} = 0V, I_D = 250 \mu A$		
Zero Gate Voltage Drain Current T _J =	+25°C	IDSS	—	_	1	μA	$V_{DS} = 50V, V_{GS} = 0V$		
Gate-Source Leakage		Igss	—	_	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 7)									
Gate Threshold Voltage	,	VGS(TH)	0.5	1.1	1.5	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$		
Static Drain-Source On-Resistance	F	RDS(ON)	—	1.3	3.5	Ω	$V_{GS} = 10V, I_D = 0.22A$		
Diode Forward Voltage		V _{SD}	_	0.8	1.2	V	$V_{GS} = 0V, I_D = 0.22A$		
DYNAMIC CHARACTERISTICS (Note 8)									
Input Capacitance		Ciss	—	23.2	—	pF			
Output Capacitance		Coss		3.1	_	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz		
Reverse Transfer Capacitance		Crss	_	2.2	—	pF			
Gate Resistance		Rg		69	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		
Total Gate Charge (V _{GS} = 4.5V)		Qg		0.45	_	nC			
Total Gate Charge (V _{GS} = 10V)		Qg	-	0.95	_	nC			
Gate-Source Charge		Qgs	-	0.10	_	nC	V _{DS} = 25V, I _D = 0.2A		
Gate-Drain Charge		Qgd	-	0.14	_	nC			
Turn-On Delay Time		tD(ON)		3.2	_	ns			
Turn-On Rise Time		t _R	_	2.5	—	ns	$V_{DS} = 25V, V_{GS} = 10V,$		
Turn-Off Delay Time		tD(OFF)	_	13.8		ns	$R_G = 50\Omega, I_D = 0.2A$		
Turn-Off Fall Time		tF	_	7.6		ns			
Reverse Recovery Time		trr	_	8.8	_	ns	I _F = 0.2A, di/dt = 100A/µs		
Reverse Recovery Charge		QRR	_	2.6		nC	I _F = 0.2A, di/dt = 100A/µs		

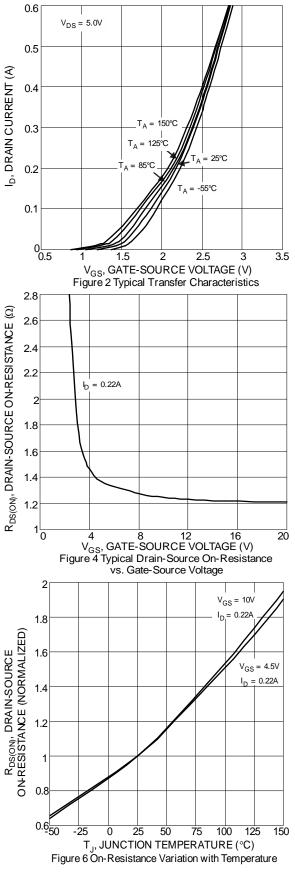
Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.

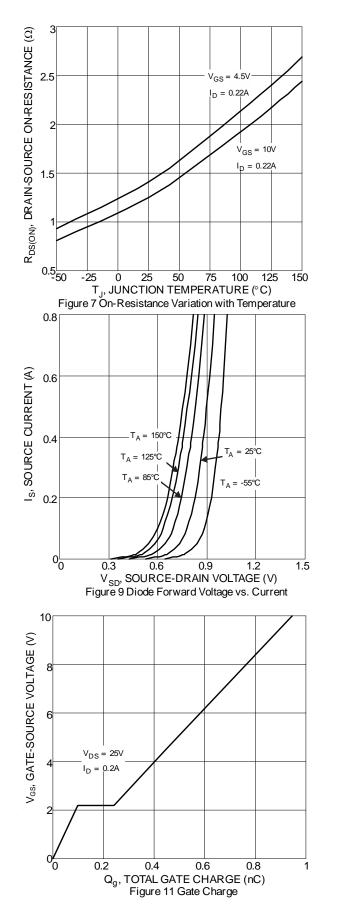
8. Guaranteed by design. Not subject to product testing.

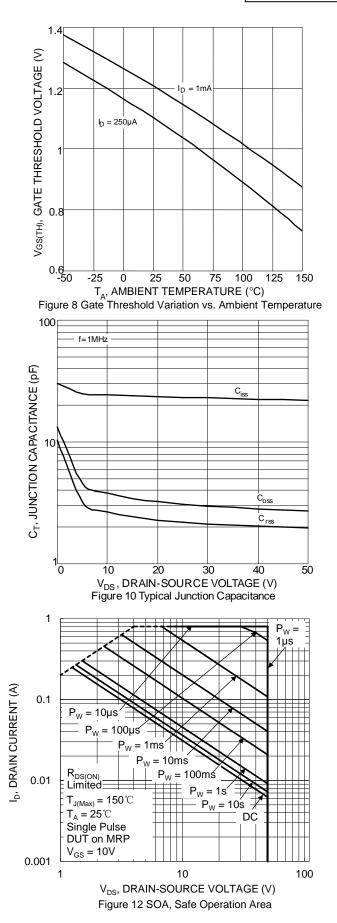




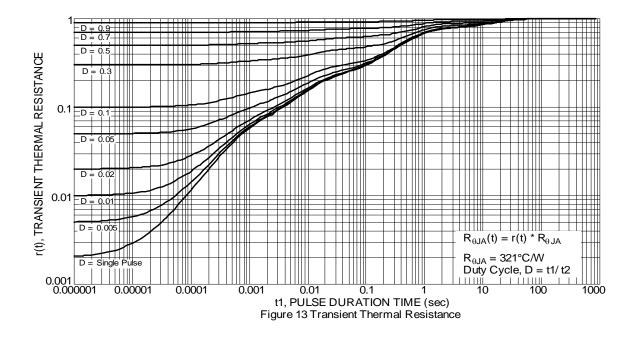








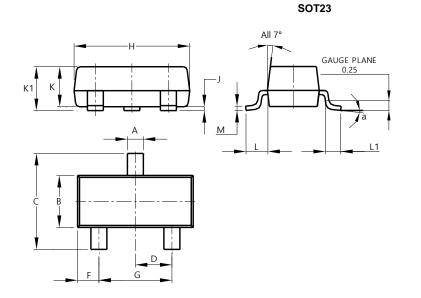






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

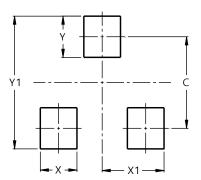


SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
К	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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